



# Thin-Film Compute-In-Memory Circuits and Systems for Large-Area Sensing Applications

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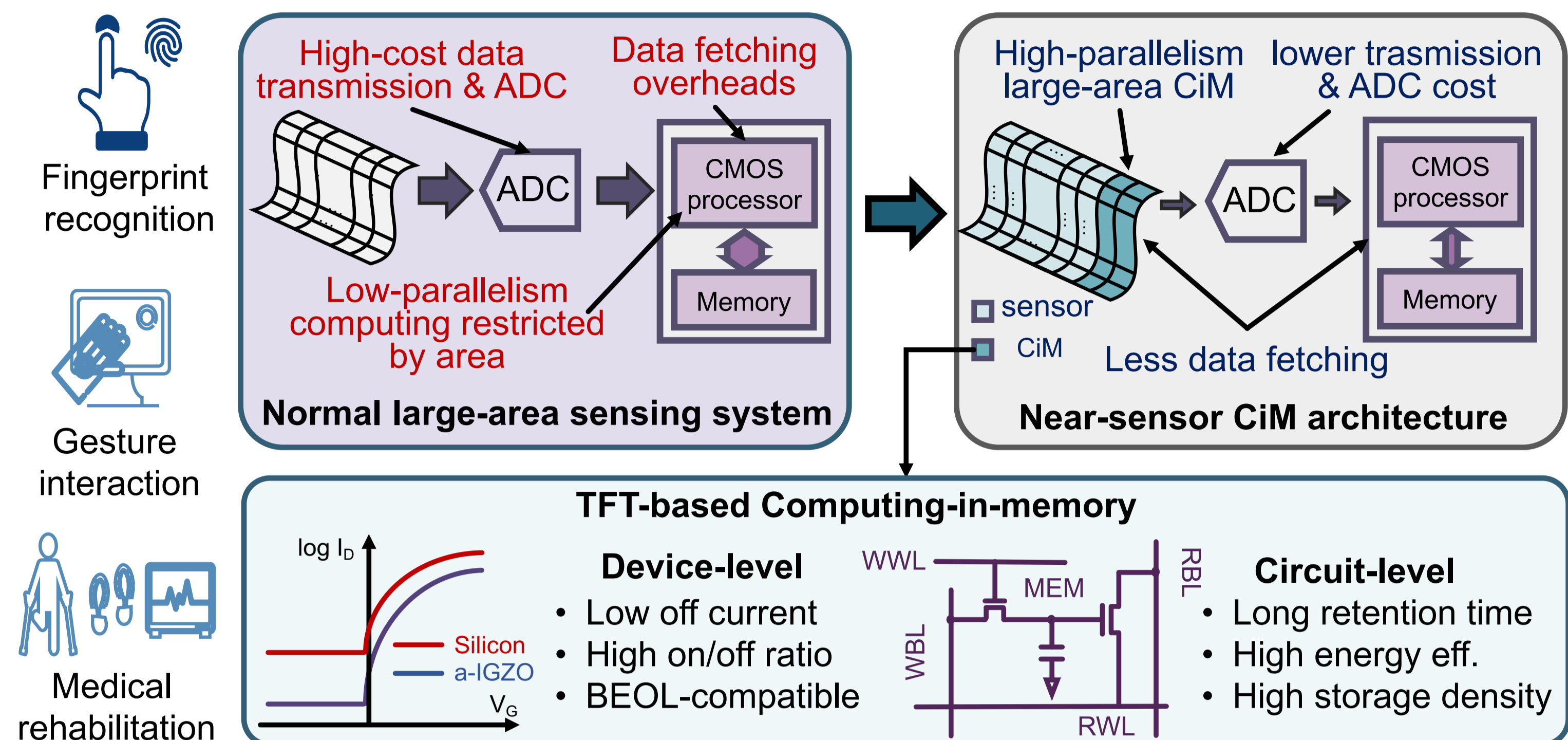
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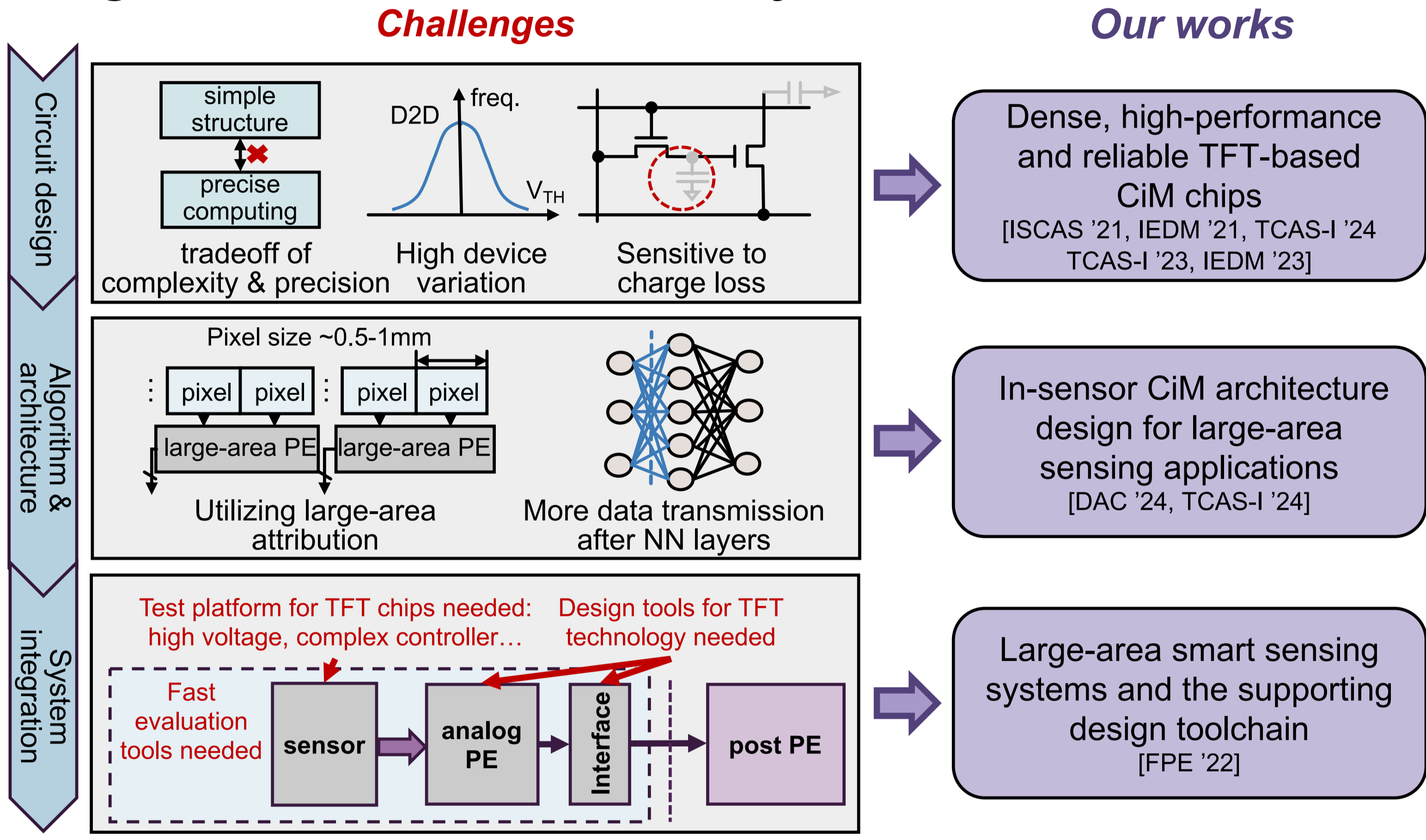
## Process more data in emerging sensing scenarios

### Thin-film transistor (TFT)-based in/near-sensor computing

- Large-area integration of sensors, memory and processors
- Ideal candidate for low-power compute-in-memory (CiM)
- Reduction of data transmission & ADC conversion



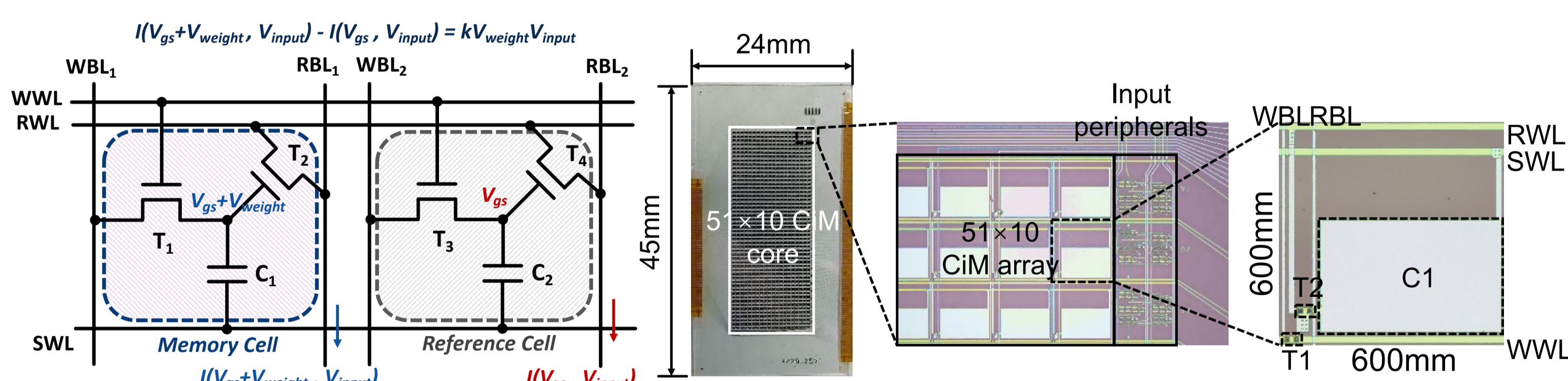
### Cross-layer exploration with perspectives from circuit, algorithm & architecture and system levels



## TFT-based CiM design with device/chip fabrication

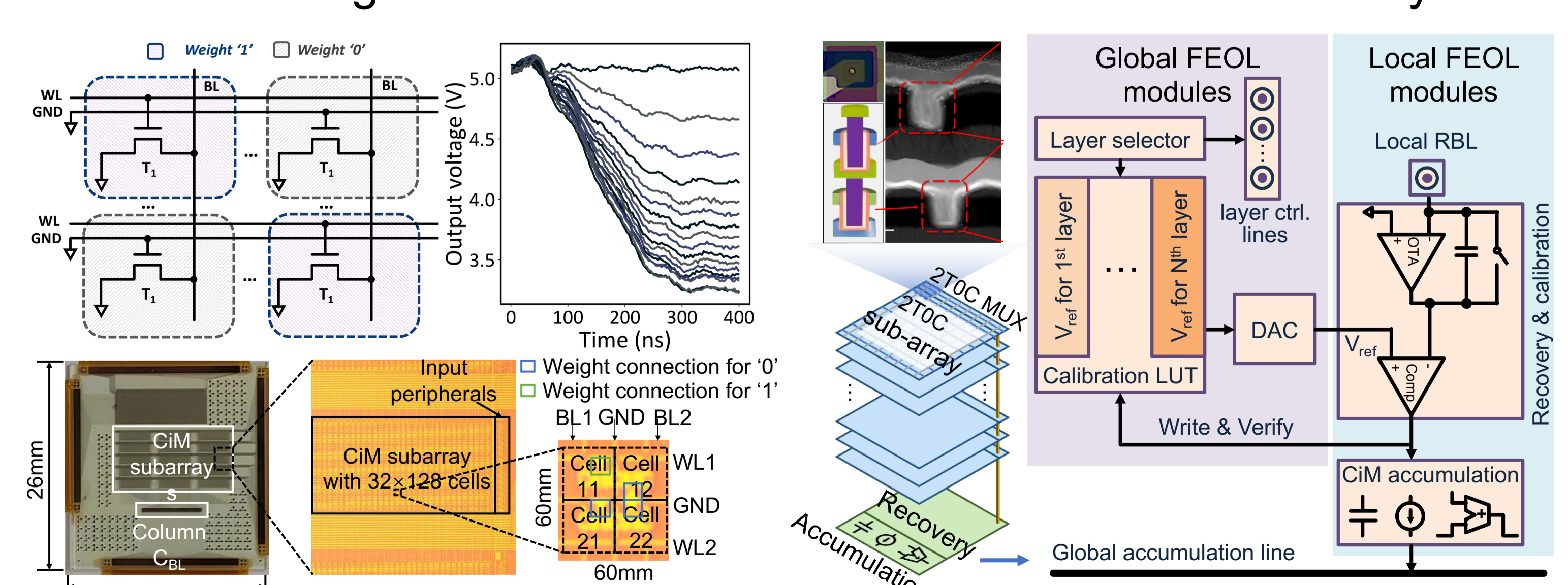
### Better computing precision (ISCAS '21 [1], TCAS-I '24 [2])

- 51x10 eDRAM CiM array with 8μm IGZO TFT (ret. time ~100s)
- High-precision 64-stage MAC operation with INL<1.5LSB



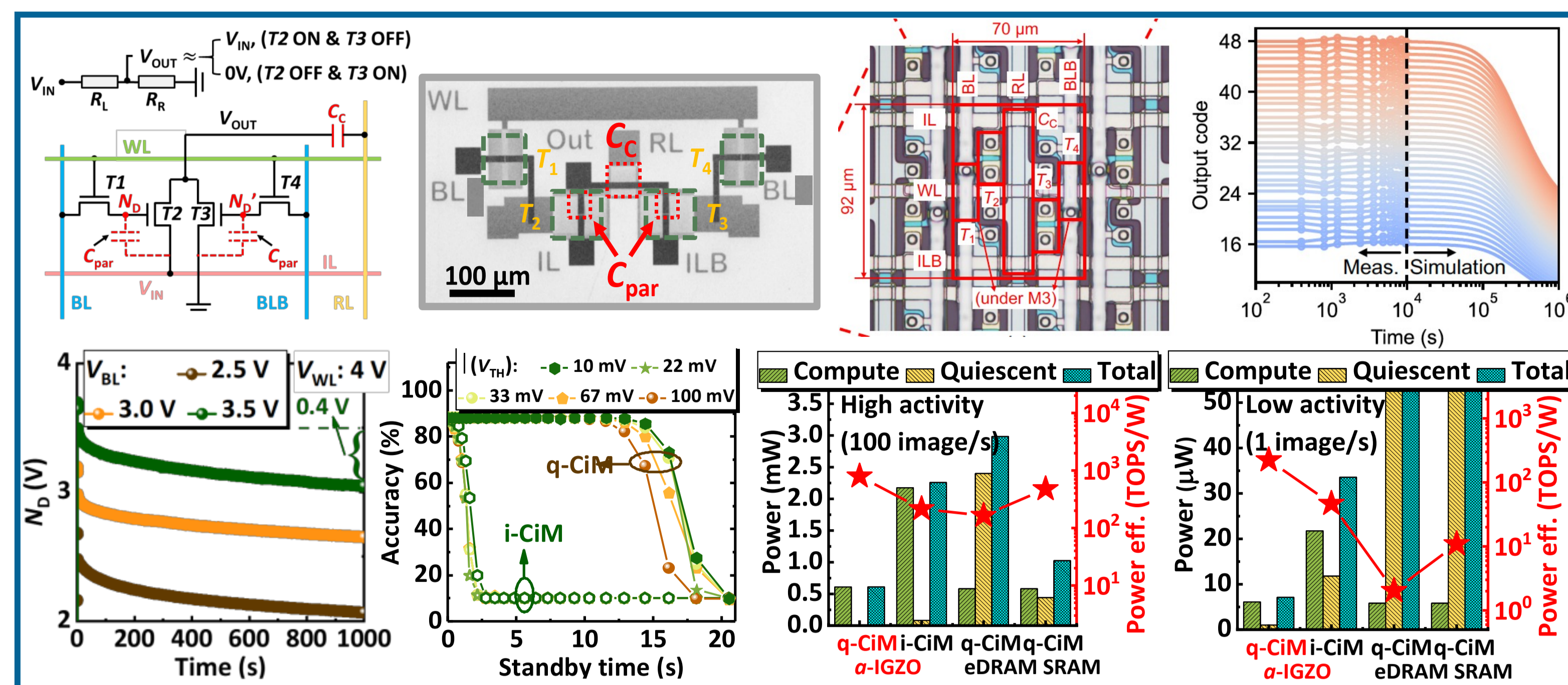
### Better memory density (TCAS-I '24 [2], IEDM '23 [6])

- Dense memory cell: 128x32 ROM CiM array with 4μm LTPS TFT
- 3D stacking: 2T0C 4F<sup>2</sup> CAA eDRAM w/ local CiM & recovery units



### Better robustness & retention (IEDM '21 [3], TCAS-I '23 [5])

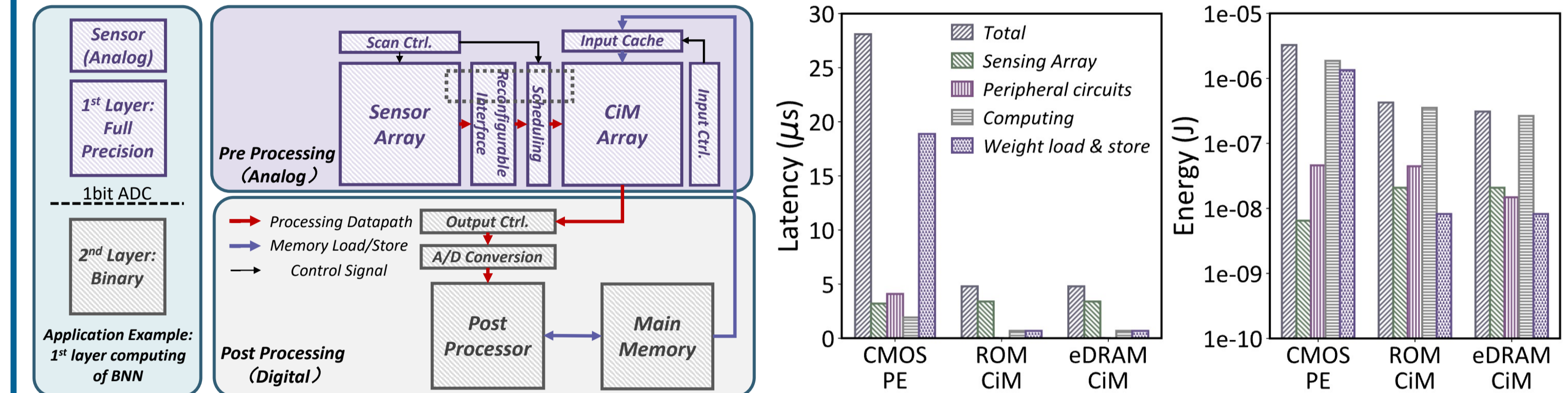
- Device & chip demonstration of charge-domain eDRAM CiM
- Great robustness to PVT-induced variation & charge leakage
- Charge-domain computing without DC power



## Architecture design for large-area smart sensing

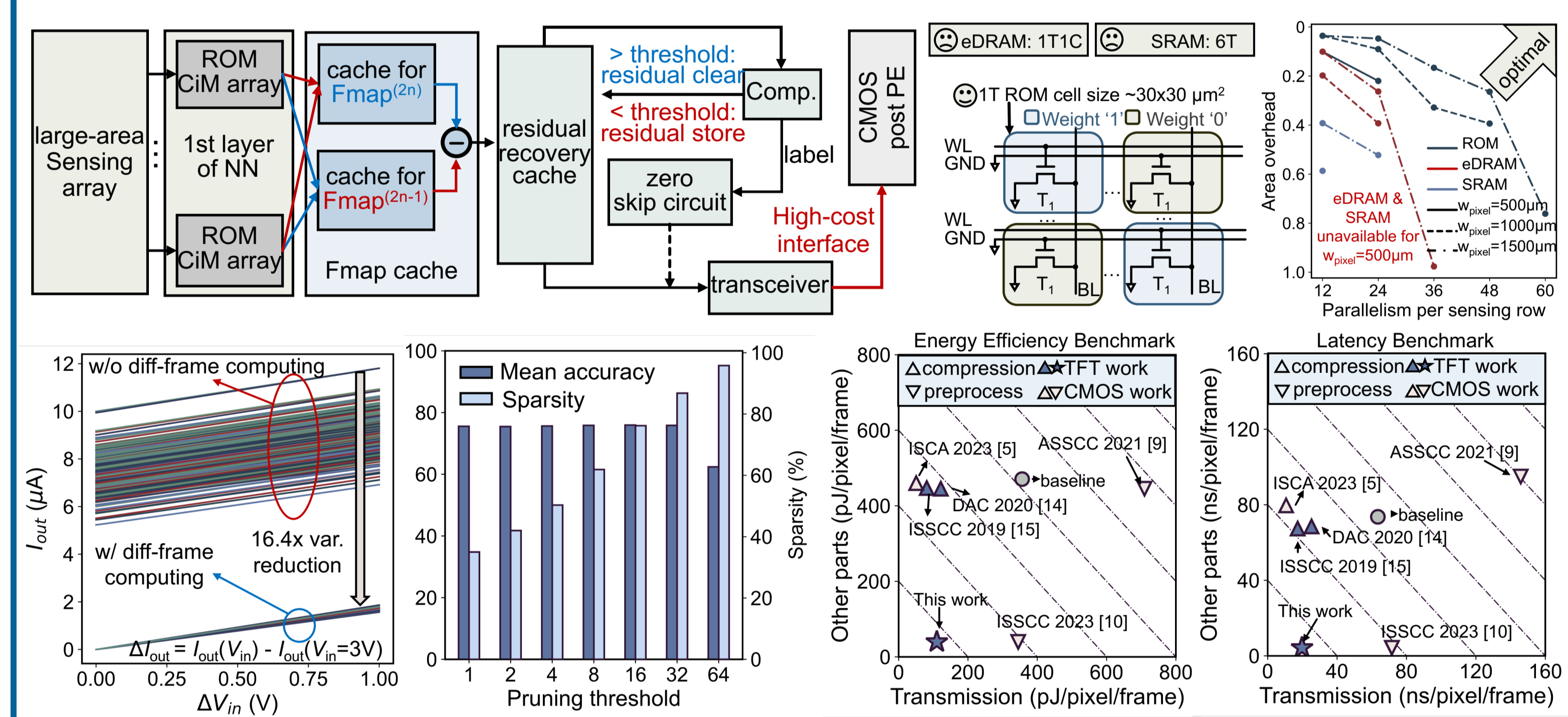
### Implementing 1<sup>st</sup> layer of BNN for data transmission/conversion reduction (TCAS-I '24 [2])

- Replace high-precision ADC with simple comparators
- 5.86x speedup and 10.78x energy efficiency improvement

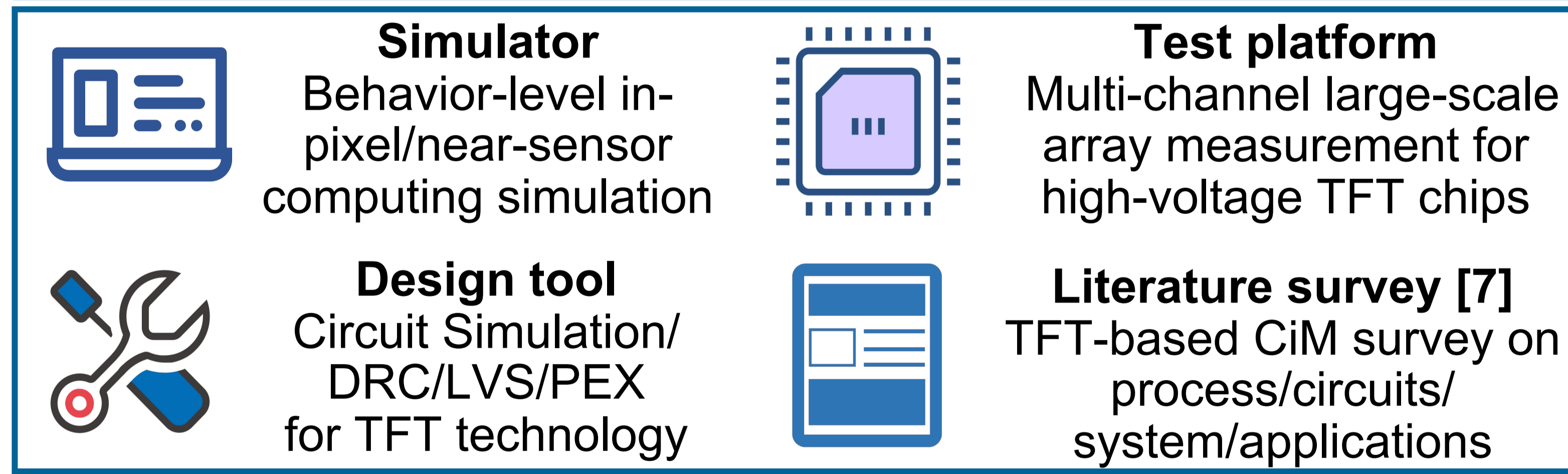


### Processing & output compression for general NN models (to appear at DAC '24 [4])

- Differential-frame computing for high reliability and output sparsity
- Bio-inspired pruning to increase sparsity by 30% on average
- Simultaneous acceleration and data compression with 3.85x speedup and 5.10x energy efficiency improvement



## Toolchain for TFT-based system integration



## Credits announcement

- In work [3], device fabrication is credited to Prof. Xiao Gong's group; in work [6], device fabrication is credited to Prof. Di Geng's group. Chip fabrication in [2][5] is credited to TIANMA Semiconductor Company.
- The presenter takes the main credits in [1][2][3][4], and is also involved in [5][6][7], which are mainly credited to Wenjun Tang, the presenter's colleague.
- The presenter and Wenjun Tang contribute equally to the toolchain for TFT-based system integration.

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**References:** [1] J. Liu *et al.*, ISCAS 2021; [2] J. Liu *et al.*, TCAS-I 2024; [3] J. Liu *et al.*, IEDM 2021; [4] J. Liu *et al.*, to appear in DAC 2024; [5] W. Tang, J. Liu *et al.*, TCAS-I 2023; [6] W. Tang\*, C. Chen\*, J. Liu\* *et al.*, IEDM 2023; [7] W. Tang, J. Liu *et al.*, FPE 2022.